



2SA1179N/2SC2812N

Bipolar Transistor (-50V, (-)150mA, Low VCE(sat), (PNP)NPN Single CPA

ON Semiconductor®
<http://onsemi.com>

Features

- Miniature package facilitates miniaturization in end products
- High breakdown voltage

Specifications () : 2SA1179N

Absolute Maximum Ratings at Ta=25°C

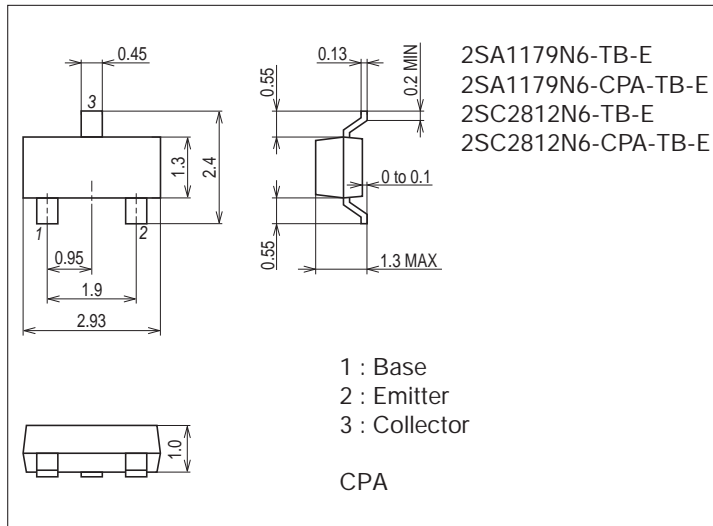
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CB0}		(-)55	V
Collector-to-Emitter Voltage	V _{CE0}		(-)50	V
Emitter-to-Base Voltage	V _{EB0}		(-)5	V
Collector Current	I _C		(-)150	mA
Collector Current (Pulse)	I _{CP}		(-)300	mA
Base Current	I _B		(-)30	mA
Collector Dissipation	P _C		200	mW
Junction Temperature	T _J		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

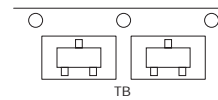
7053-001



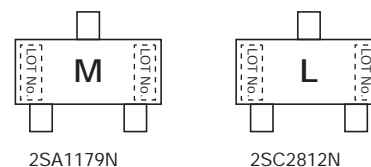
Product & Package Information

- Package : CPA
- JEITA, JEDEC : SC-59, TO-236, SOT-23, TO-236AB
- Minimum Packing Quantity : 3,000 pcs./reel

Packing Type: TB



Marking



2SA1179N / 2SC2812N

Electrical Characteristics at Ta=25°C

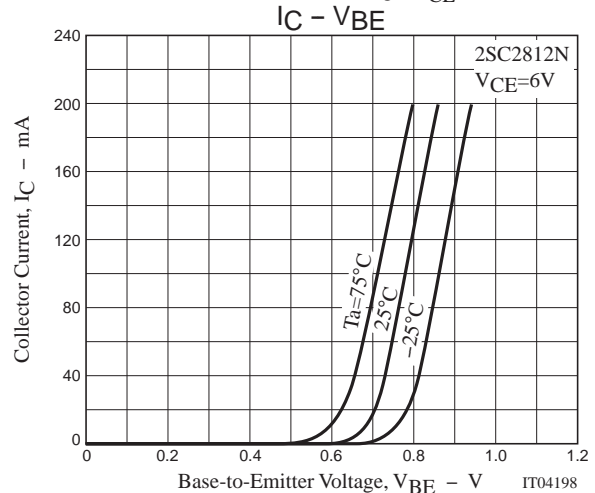
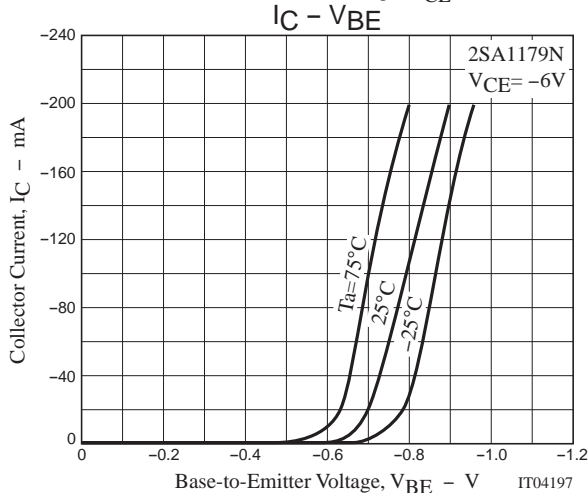
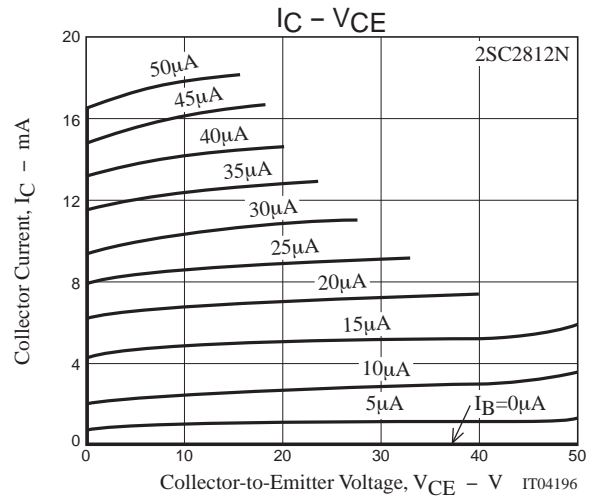
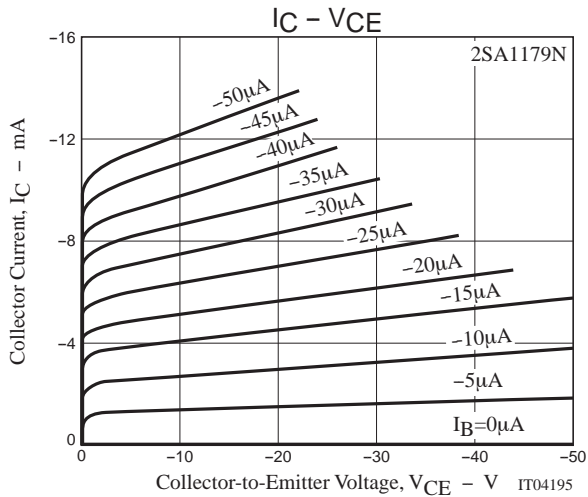
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	ICBO	V _{CB} =(-)35V, I _E =0A			(-)0.1	μA
Emitter Cutoff Current	I _{EBO}	V _{EB} =(-)4V, I _C =0A			(-)0.1	μA
DC Current Gain	h _{FE}	V _{CE} =(-)6V, I _C =(-)1mA	200		400	
Gain-Bandwidth Product	f _T	2SC2812N : V _{CE} =6V, I _C =1mA		100		MHz
		2SA1179N : V _{CE} =-6V, I _C =-10mA		(180)		MHz
Output Capacitance	C _{ob}	V _{CB} =(-)6V, f=1MHz		(4.0)3.0		pF
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =(-)50mA, I _B =(-)5mA		(-0.15)0.1	(-)0.5	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =(-)50mA, I _B =(-)5mA			(-)1.0	V
Collector-to-Base Breakdown Voltage	V _{(BR)CBO}	I _C =(-)10μA, I _E =0A	(-)55			V
Collector-to-Emitter Breakdown Voltage	V _{(BR)CEO}	I _C =(-)1mA, R _{BE} =∞	(-)50			V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E =(-)10μA, I _C =0A	(-)5			V

* : The 2SA1179N / 2SC2812N are classified by 1mA h_{FE} as follows :

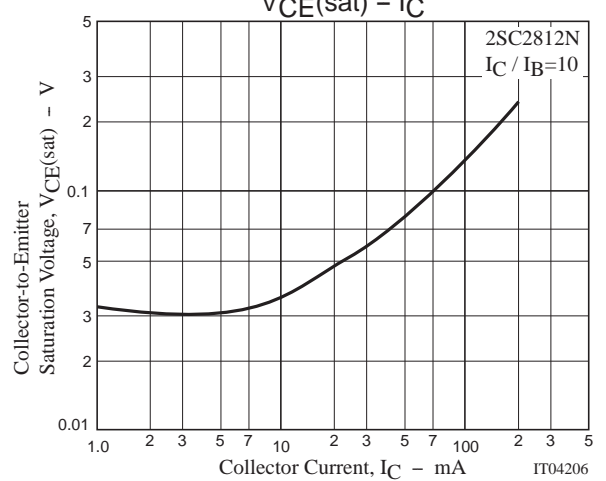
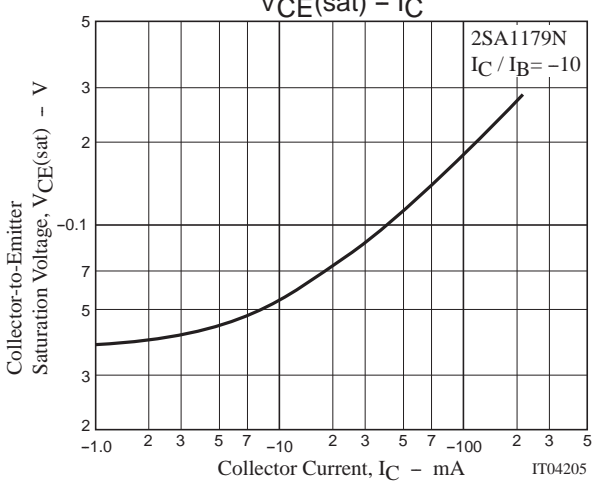
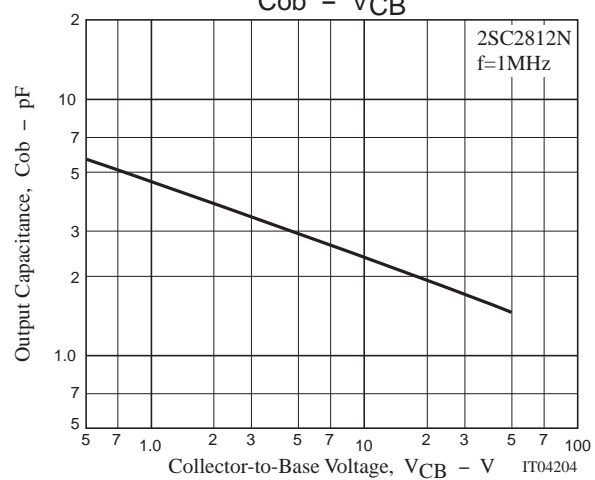
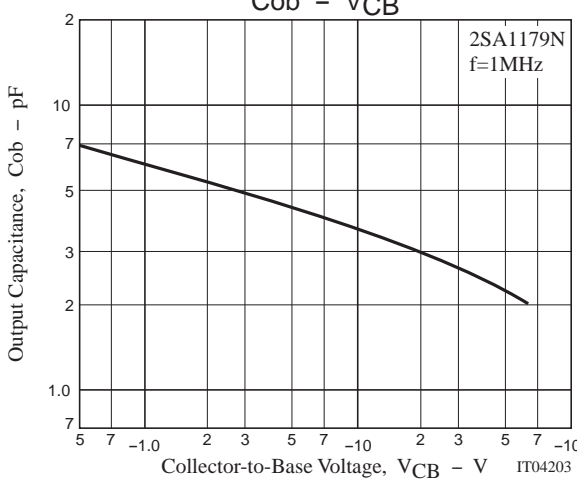
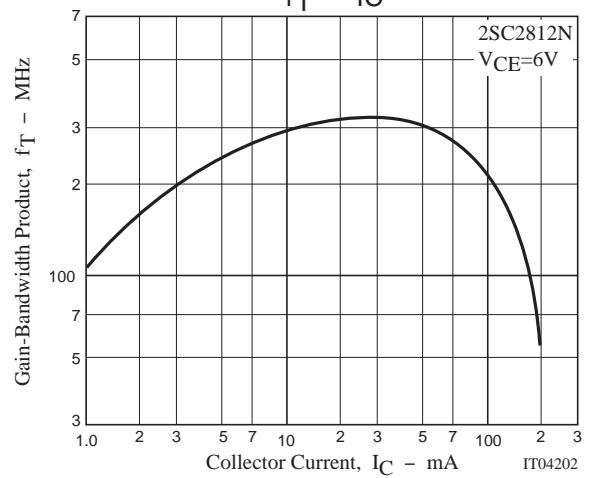
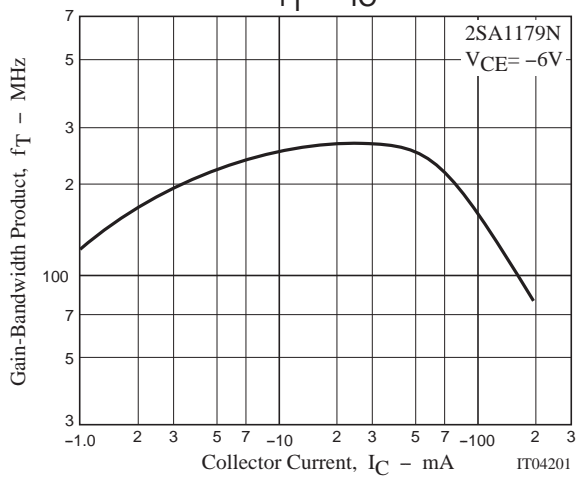
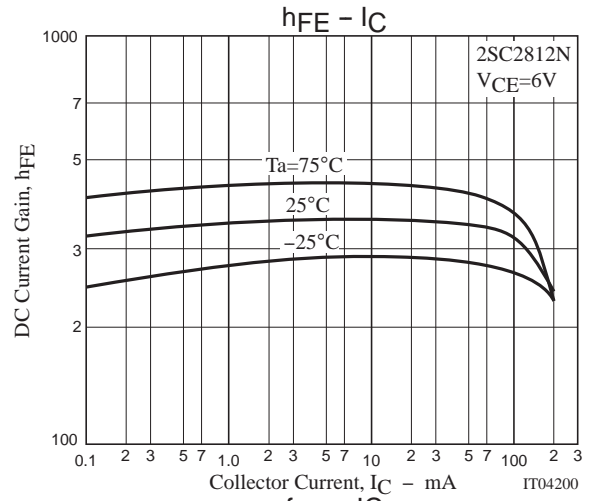
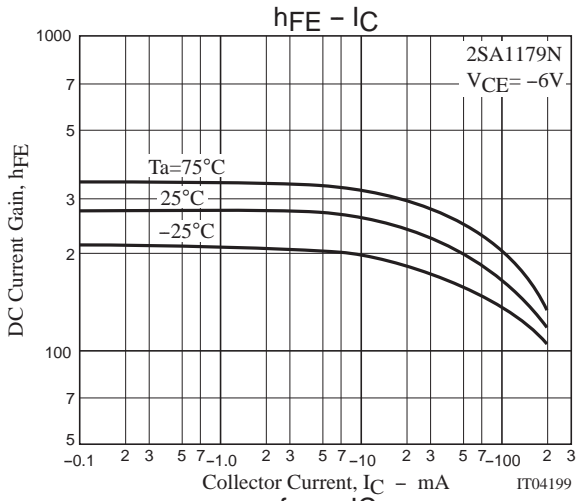
Rank	6
h _{FE}	200 to 400

Ordering Information

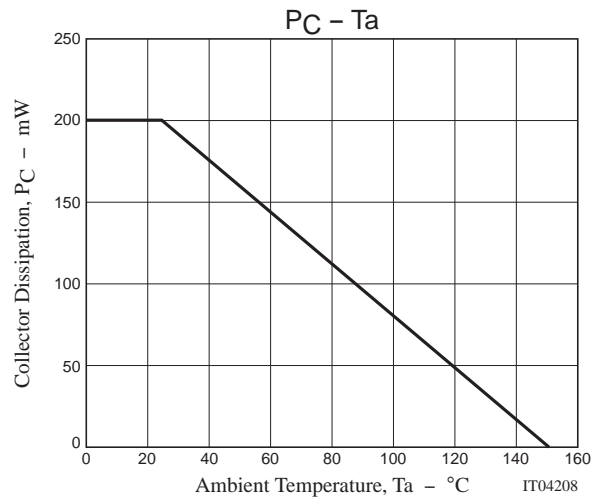
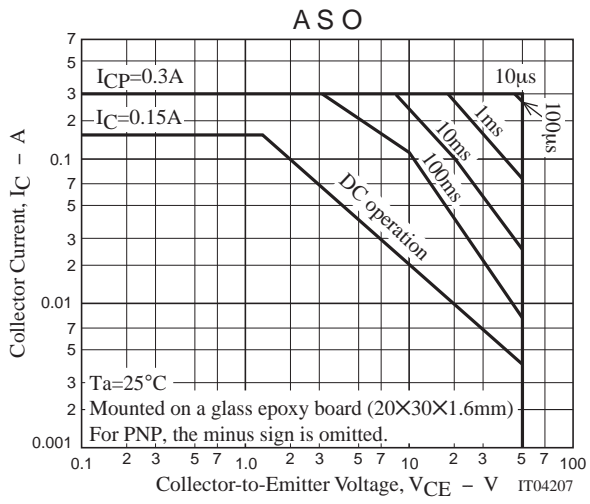
Device	Package	Shipping	memo
2SA1179N6-TB-E	CPA	3,000pcs./reel	Pb Free
2SA1179N6-CPA-TB-E	CPA	3,000pcs./reel	
2SC2812N6-TB-E	CPA	3,000pcs./reel	
2SC2812N6-CPA-TB-E	CPA	3,000pcs./reel	



2SA1179N / 2SC2812N



2SA1179N / 2SC2812N



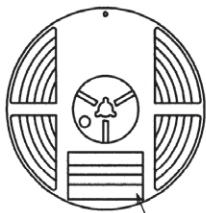
Embossed Taping Specification

2SA1179N6-TB-E, 2SA1179N6-CPA-TB-E, 2SC2812N6-TB-E, 2SC2812N6-CPA-TB-E

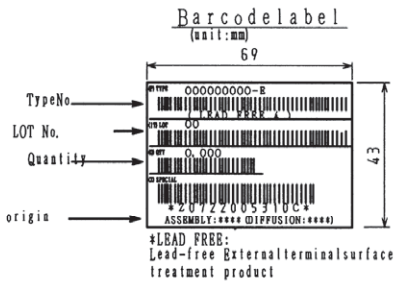
1. Packing format

Storage package Outline name	Carriertape Typenumber	Maximum Number of Devices contained (PCS)			Packing format	
		Reel	Innerbox	Outerbox	Innerbox BOX (C-)	Outerbox BOX (A-7)
CPA	CPA	3,000	15,000	90,000	5 reels contained Dimensions: mm (external) 183×72×185	6 innerboxes contained Dimensions: mm (external) 440×195×210

Packing method



Barcode label



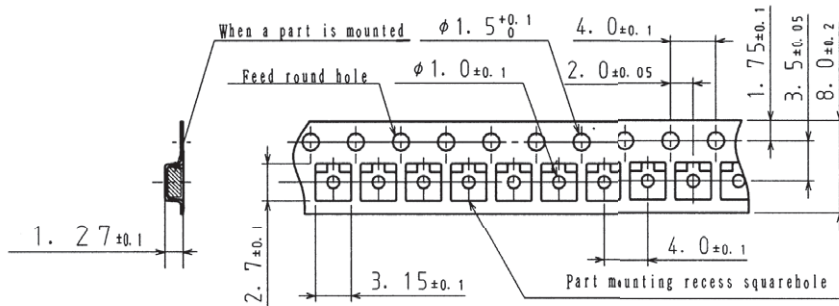
Shipping Label

It is a label at the time of factory shipments
The form of a label may change in physical
distribution process

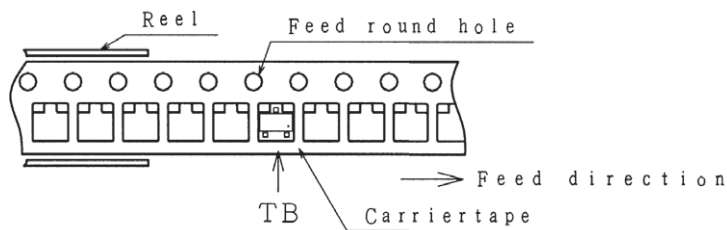


2. Taping structure

2-1. Carrier tape size (unit: mm)



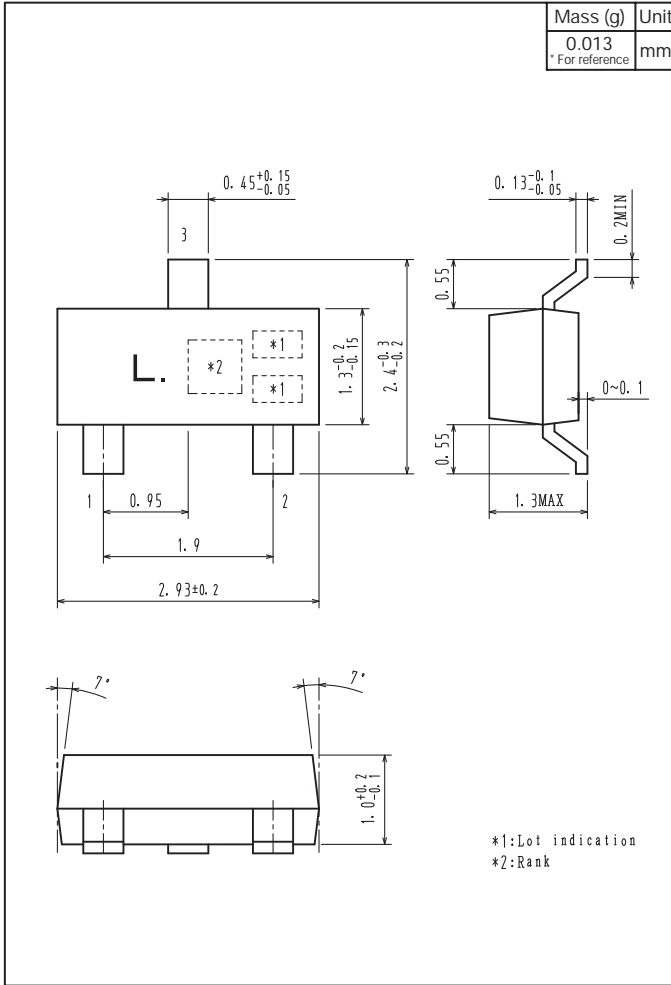
2-2. Parts placement direction



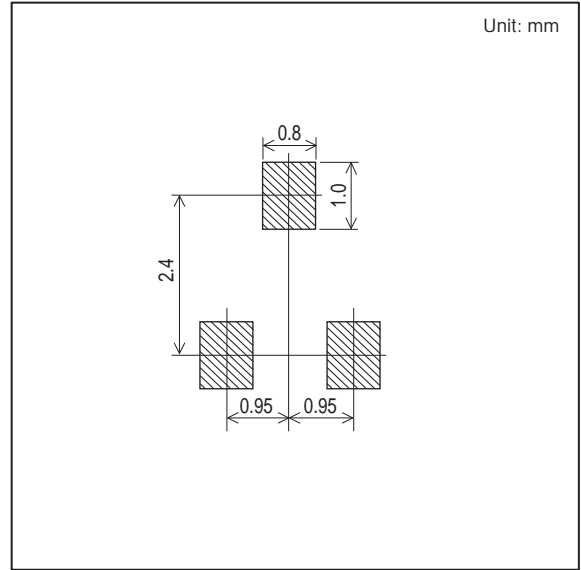
2SA1179N / 2SC2812N

Outline Drawing

2SA1179N6-TB-E, 2SA1179N6-CPA-TB-E, 2SC2812N6-TB-E, 2SC2812N6-CPA-TB-E



Land Pattern Example



ON Semiconductor and the ON logo are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.